# 2SC4829

## Silicon NPN Epitaxial

# **HITACHI**

ADE-208-1123 (Z) 1st. Edition Mar. 2001

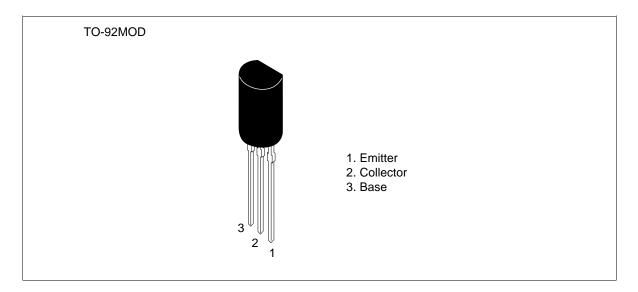
#### **Application**

High frequency amplifier

#### **Features**

- High frequency characteristics
  f<sub>T</sub> = 1100 MHz Typ
- High voltage and small output capacitance  $V_{\text{CEO}} = 100 \text{ V}, \text{ Cob} = 4.2 \text{ pF Typ}$
- Suitable for wide band video amplifier

#### **Outline**





## 2SC4829

## **Ordering Information**

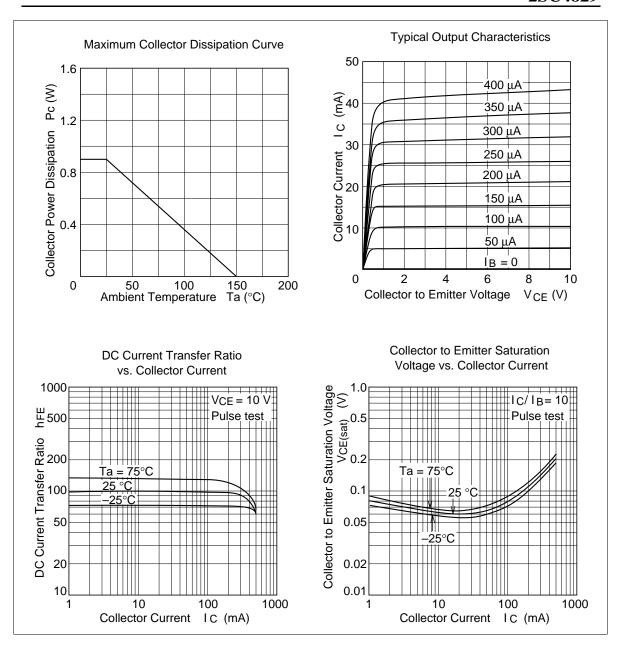
	h <sub>FE</sub>
2SC4829B	60 to 120
2SC4829C	100 to 200

## Absolute Maximum Ratings ( $Ta = 25^{\circ}C$ )

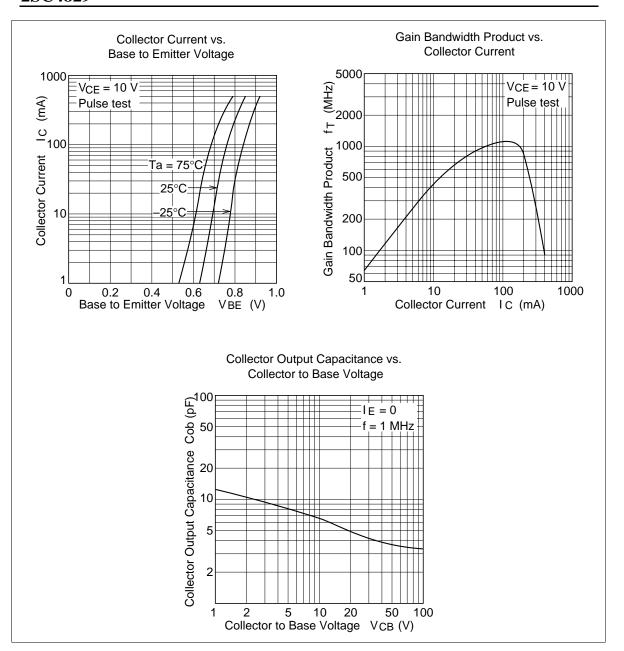
Item	Symbol	Ratings	Unit	
Collector to base voltage	$V_{\text{CBO}}$	100	V	
Collector to emitter voltage	$V_{\text{CEO}}$	100	V	
Emitter to base voltage	$V_{EBO}$	3	V	
Collector current	I <sub>c</sub>	0.2	А	
Collector peak current	i <sub>C (peak)</sub>	0.5	А	
Collector power dissipation	P <sub>c</sub>	0.9	W	
Junction temperature	Tj	150	°C	
Storage temperature	Tstg	-55 to +150	°C	

## **Electrical Characteristics** ( $Ta = 25^{\circ}C$ )

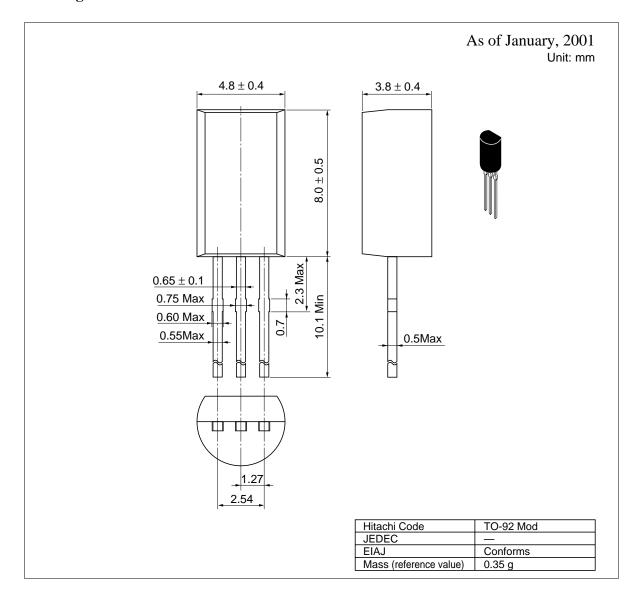
Item		Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage		$V_{\text{(BR)CBO}}$	100	_	_	V	$I_{c} = 10 \ \mu A, \ I_{E} = 0$
Collector to emitter breakdown voltage		$V_{(BR)CEO}$	100	_	_	V	$I_{c}$ = 1 mA, $R_{BE}$ = $\infty$
Emitter cutoff current		I <sub>EBO</sub>	_	_	10	μΑ	$V_{EB} = 3 \text{ V}, I_{C} = 0$
Collector cutoff	Collector cutoff current		_	_	1.0	μΑ	$V_{CB} = 80 \text{ V}, I_{E} = 0$
DC current transfer ratio	2SC4829B	h <sub>FE</sub>	60	_	120		$V_{CE} = 10 \text{ V}, I_{C} = 10 \text{ mA}$
	2SC4829C	h <sub>FE</sub>	100	_	200		
Base to emitter voltage		V <sub>BE</sub>	_	_	1.0	V	$V_{CE} = 10 \text{ V}, I_{C} = 10 \text{ mA}$
Collector to emitter saturation voltage		$V_{\text{CE(sat)}}$	_	_	1.0	V	I <sub>C</sub> = 100 mA, I <sub>B</sub> = 10 mA
Gain bandwidth product		f <sub>T</sub>	800	1100	_	MHz	V <sub>CE</sub> = 10 V, I <sub>E</sub> = 100 mA
Collector output capacitance		Cob	_	4.2	6.0	pF	$V_{CB} = 30 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$



#### 2SC4829



#### **Package Dimensions**



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